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### **Dynamically Adjustable 6-Bit VID Step-Down Controller**

### **General Description**

The MAX8720 step-down controller is intended for core CPU DC-DC converters in notebook computers. It features a dynamically adjustable output, ultra-fast transient response, high DC accuracy, and the high efficiency needed for leading-edge CPU core power supplies. Maxim's proprietary Quick-PWM™ quick-response, constant-on-time, PWM control scheme handles wide input/output voltage ratios with ease and provides 100ns "instant-on" response to load transients while maintaining a relatively constant switching frequency.

The output voltage can be dynamically adjusted through the 6-bit digital-to-analog converter (DAC) over a 0.275V to 1.850V range in 25mV steps. The MAX8720 has independent four-level logic inputs for setting the suspend voltage (S0-S1). Precision slew-rate control provides "just-in-time" arrival at the new DAC setting, minimizing surge currents to and from the battery. The internal DAC of the MAX8720 is synchronized to the slew-rate clock for improved operation under aggressive power management of newer chipsets and operating systems that can make incomplete mode transitions. Remote feedback and ground-sense inputs allow easy compensation for IR drops in PC board traces.

Single-stage buck conversion allows these devices to directly step down high-voltage batteries for the highest possible efficiency. Alternatively, two-stage conversion (stepping down the 5V system supply instead of the battery) at a higher switching frequency allows the minimum possible physical size.

The MAX8720 is available in a 28-pin QSOP or 36-pin 6mm x 6mm thin QFN package.

### **Applications**

**CPU Core Supply Converters GPU Core Supply Converters** Notebook and Subnotebook Computers

Quick-PWM is a trademark of Maxim Integrated Products, Inc.

Pin Configurations appear at end of data sheet.

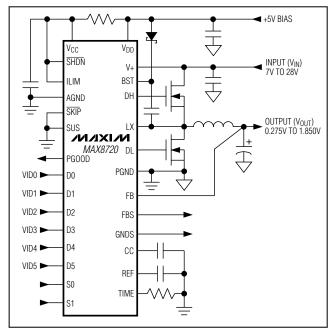
### **Features**

- ♦ Quick-PWM Architecture
- ♦ ±1% Vout Accuracy Over Line and Load
- ♦ 6-Bit On-Board DAC with Input Muxes
- ♦ Precision-Adjustable Vout Slew Control
- ♦ 0.275V to 1.850V Output Adjust Range
- ♦ Remote Feedback and Ground Sense
- **♦ Supports Voltage-Positioned Applications**
- ♦ 2V to 28V Battery Input Range
- ♦ 200kHz/300kHz/550kHz/1000kHz Switching Frequency
- ♦ Over/Undervoltage Protection
- ♦ Drives Large Synchronous-Rectifier FETs
- ♦ 800µA (typ) ICC Supply Current
- ♦ 10µA (typ) Shutdown Supply Current
- ♦ 2V ±0.75% Reference Output
- ♦ PGOOD Blanking During Transition

### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX8720EEI	-40°C to +85°C	28 QSOP
MAX8720ETX	-40°C to +85°C	36 Thin QFN 6mm x 6mm

### **Minimal Operating Circuit**



MIXIM

Maxim Integrated Products 1

### **ABSOLUTE MAXIMUM RATINGS** (Note 1)

	( )
V <sub>CC</sub> to AGND	0.3V to +6V
V <sub>DD</sub> to PGND	0.3V to +6V
AGND to PGND	0.3V to +0.3V
V+ to PGND	0.3V to +30V
SHDN to AGND	0.3V to +16V
D0-D5, PGOOD, SUS, SKIP to AGND	0.3V to +6V
FB, FBS, GNDS to AGND	0.3V to (V <sub>CC</sub> + 0.3V)
CC, ILIM, REF, TIME to AGND	0.3V to $(V_{CC} + 0.3V)$
S0, S1, TON to AGND	0.3V to (V <sub>CC</sub> + 0.3V)
BST to PGND	0.3V to +36V
LX to BST	6V to +0.3V

DH to LX	-0.3V to (BST + 0.3V)
DL to PGND	$-0.3V$ to $(V_{DD} + 0.3V)$
REF Short Circuit to AGND	Continuous
Continuous Power Dissipation (T <sub>A</sub> = +70°C	
28-Pin QSOP (derate 10.8mW/°C above	+70°C)860mW
36-Pin TQFN (derate 26.3mW/°C above	+70°C)2105mW
Operating Temperature	
Extended Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	
Lead Temperature (soldering, 10s)	+300°C

Note 1: For the MAX8720EEI, AGND and PGND refer to a single pin designated GND.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1, V+ = 15V,  $\overline{SHDN} = \overline{SKIP} = V_{DD} = V_{CC} = +5V$ ,  $V_{OUT} = 1.25V$ ,  $T_A = 0^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
PWM CONTROLLER		•					•
January Velta de Danas		Battery voltage, V+		2		28	
Input Voltage Range		V <sub>CC</sub> , V <sub>DD</sub>		4.5		5.5	V
			DAC codes from 0.9V to 1.85V	-1		+1	%
DC Output Voltage Accuracy		V+ = 4.5V to 28V, includes load regulation error	DAC codes from 0.45V to 0.875V	-10		+10	\/
		rogulation on or	DAC codes from 0.275V to 0.425V	-18		+18	mV
Line Regulation Error		$V_{CC} = 4.5V \text{ to } 5.5V,$	V+ = 4.5V to 28V		5		mV
Remote-Sense Voltage Error		FB to FBS or AGND	to GNDS = 0 to 25mV		3		mV
FBS Input Bias Current		FB, FBS		-0.2		+0.2	μΑ
GNDS Input Bias Current		GNDS		-1		+1	μΑ
FB Input Resistance				115	180	265	kΩ
		150kHz, R <sub>TIME</sub> = 120k $\Omega$ 818kHz, R <sub>TIME</sub> = 22k $\Omega$ 38kHz, R <sub>TIME</sub> = 470k $\Omega$		-8		+8	
TIME Frequency Accuracy				-12		+12	%
				-12		+12	]
		V+ = 5V, FB = 1.25V, TON = GND (1000kHz)		230	260	290	
On-Time (Note 2)	ton		TON = REF (550kHz)	165	190	215	no
	ton V+ = 12V, FB = 1.25V	,	TON = open (300kHz)	320	355	390	ns
		TON = V <sub>CC</sub> (200kHz)	465	515	565		

### **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1, V+ = 15V,  $\overline{SHDN} = \overline{SKIP} = V_{DD} = V_{CC} = +5V$ ,  $V_{OUT} = 1.25V$ ,  $T_A = 0^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	CONE	DITIONS	MIN	TYP	MAX	UNITS
Minimum Off-Time (Note 2)	toff(MIN)	TON = V <sub>CC</sub> , open, or or 550kHz)	TON = V <sub>CC</sub> , open, or REF (200kHz, 300kHz, or 550kHz)		400	500	ns
		TON = GND (1000kH	lz)		300	375	
BIAS AND REFERENCE				•			
Quiescent Supply Current (V <sub>CC</sub> )	Icc	FB forced above their	r regulation points		700	1200	μΑ
Quiescent Supply Current (V <sub>DD</sub> )	I <sub>DD</sub>	FB forced above their	r regulation points		<1	5	μΑ
Quiescent Battery Supply Current (V+)	I <sub>+</sub>				25	40	μΑ
Shutdown Supply Current (V <sub>CC</sub> )	Icc	SHDN = GND			10	25	μΑ
Shutdown Supply Current (VDD)	I <sub>DD</sub>	SHDN = GND			<1	5	μΑ
Shutdown Battery Supply Current (V+)	I <sub>+</sub>	SHDN = GND, V <sub>CC</sub> =	: V <sub>DD</sub> = 0V or 5V		<1	5	μΑ
Defenses Nelless		$V_{CC} = 4.5V \text{ to } 5.5V,$	$T_A = +25^{\circ}C \text{ to } +85^{\circ}C$	1.985	2.00	2.015	\ /
Reference Voltage	VREF	I <sub>REF</sub> = 0	$T_A = 0^{\circ}C \text{ to } +85^{\circ}C$	1.98	2.00	2.02	V
Reference Load Regulation	$\Delta V_{REF}$	$I_{REF} = 0$ to $50\mu A$				0.01	V
REF Sink Current		REF in regulation		10			μΑ
FAULT DETECTION							
V <sub>CC</sub> Undervoltage-Lockout Threshold		Rising edge, hysteres disabled below this le		4.1		4.4	٧
Output Overvoltage Trip Threshold				2.20	2.25	2.30	V
Output Overvoltage Fault- Propagation Delay	tovp	FB forced 2% above	regulation		10		μs
Output Undervoltage-Protection Trip Threshold		With respect to unloa	ded output voltage	65	70	75	%
Output Undervoltage Fault- Propagation Delay	tuvp	FB forced 2% below t	trip threshold		10		μs
PGOOD Transition Blanking Time		After X = Y, clock spe	eed set by RTIME		8		clk
PGOOD Lower Trip Threshold		Measured at FB with respect to unloaded output voltage, hysteresis = 1%		-17	-15	-13	%
PGOOD Upper Trip Threshold		Measured at FB with respect to unloaded output voltage, hysteresis = 1%		+13	+15	+17	%
PGOOD Propagation Delay	tpgood	Falling edge, 50mV overdrive			10		μs
PGOOD Output Low Voltage		Isink = 4mA				0.4	V
PGOOD Leakage Current	IPGOOD	High state, PGOOD forced to 5.5V				1	μΑ
Thermal-Shutdown Threshold	TSHDN	Hysteresis = 10°C			+150		°C
CURRENT LIMIT	•	•					
ILIM Adjustment Range				0.5		V <sub>REF</sub>	V

### **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1, V+ = 15V,  $\overline{SHDN} = \overline{SKIP} = V_{DD} = V_{CC} = +5V$ ,  $V_{OUT} = 1.25V$ ,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	CONE	DITIONS	MIN	TYP	MAX	UNITS	
Current Limit Throphold (Fixed)	\/	V <sub>PGND</sub> - V <sub>LX</sub> ,	$T_A = +25^{\circ}C \text{ to } +85^{\circ}C$	90	100	110	m\/	
Current-Limit Threshold (Fixed)	V <sub>LIMIT</sub>	ILIM = V <sub>C</sub> C	$T_A = 0$ °C to +85°C	85		115	mV	
Current-Limit Threshold	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	M. A. M.	V <sub>ILIM</sub> = 2.00V	165	200	230	/	
(Adjustable)	V <sub>LIMIT</sub>	VPGND - VLX	VILIM = 0.50V	35	50	65	mV	
		V <sub>LX</sub> - V <sub>PGND</sub> , SKIP =	ILIM = V <sub>CC</sub> ,	-140	-117	-90	mV	
Current-Limit Threshold (Negative)	V <sub>NEG</sub>	V <sub>LX</sub> - V <sub>PGND</sub> , <del>SKIP</del> = percent of current lim	V <sub>CC</sub> , adjustable mode, iit		-117		%	
Current-Limit Threshold (Zero Crossing)	$V_{ZX}$	V <sub>PGND</sub> - V <sub>LX</sub> , <del>SKIP</del> =	GND		4		mV	
Current-Limit Default Switchover Threshold				3	V <sub>CC</sub> -	V <sub>CC</sub> - 0.4	V	
ILIM Leakage Current						0.1	μΑ	
GATE DRIVERS								
DH Gate-Driver On-Resistance	Davi	DCT I V forced to EV	QSOP package		1.0	3.5		
(Note 3)	R <sub>DH</sub>	BST-LX forced to 5V	TQFN package		1.0	4.5	Ω	
		DI high state	QSOP package		1.0	3.5		
DL Gate-Driver On-Resistance (Note 3)	R <sub>DL</sub>	DL, high state TQFN package			1.0	4.0	Ω	
(Note 3)		DL, low state			0.4	1.0		
DH Gate-Driver Source/Sink Current	IDH	DH forced to 2.5V, BS	ST-LX forced to 5V		2		А	
DL Gate-Driver Source Current	I <sub>DL</sub> (SOURCE)	DL forced to 2.5V			1.6		А	
DL Gate-Driver Sink Current	IDL (SINK)	DL forced to 2.5V			4		А	
Dood Times		DL rising			35			
Dead Time	tDEAD	DH rising			26		ns	
INPUTS AND OUTPUTS								
		Logic high		2.4				
SHDN Input Level	VSHDN	Logic low				0.4	V	
		No-fault mode		12		15		
Logic Input High Voltage	VIH	D0-D5, SKIP, SUS		2.4			V	
Logic Input Low Voltage	V <sub>IL</sub>	D0-D5, SKIP, SUS				0.8	V	
Logic Input Current		D0-D5, SKIP, SUS		-1		+1	μΑ	
			High	V <sub>CC</sub> - 0.2				
Four-Level Input Logic		TON, S0, S1	Open	3.15		3.85	V	
			REF	1.65		2.35		
			GND			0.5	1	
Input Leakage Current		SHDN, TON, S0, S1 f	orced to V <sub>CC</sub> or GND	-3		+3	μΑ	

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### **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1, V+ =15V,  $\overline{SHDN} = \overline{SKIP} = V_{DD} = V_{CC} = +5V$ ,  $V_{OUT} = 1.25V$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .) (Note 4)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
PWM CONTROLLER							
Input Voltage Dange		Battery Voltage, V+		2		28	V
Input Voltage Range		V <sub>CC</sub> , V <sub>DD</sub>		4.5		5.5	V
			DAC codes from 0.9V to 1.85V	-1		+1	%
DC Output Voltage Accuracy		V+ = 4.5V to 28V, includes load regulation error	DAC codes from 0.45V to 0.875V	-15		+15	, no.) /
		Togulation on of	DAC codes from 0.275V to 0.425V	-18		+18	mV
FB Input Resistance				115		265	kΩ
		150kHz, R <sub>TIME</sub> = 120	OkΩ	-8		+8	
TIME Frequency Accuracy		818kHz, R <sub>TIME</sub> = 22	kΩ	-12		+12	%
		38kHz, R <sub>TIME</sub> = 470	kΩ	-12		+12	
		V+ = 5V, FB = 1.25V (1000kHz)	/, TON = GND	230		290	
On-Time (Note 2)	ton	V+ = 12V, FB = 1.25V	TON = REF (550kHz)	165		215	
			TON = open (300kHz)	320		390	ns
			TON = V <sub>CC</sub> (200kHz)	465		565	
Minimum Off-Time (Note 2)	toff(MIN)	TON = V <sub>CC</sub> , open, o or 550kHz)	r REF (200kHz, 300kHz,			500	ns
		TON = GND (1000kl	⊣z)			375	
BIAS AND REFERENCE							
Quiescent Supply Current (V <sub>CC</sub> )	Icc	FB forced above the	ir regulation points			1300	μΑ
Quiescent Supply Current (VDD)	IDD	FB forced above the	ir regulation points			5	μΑ
Quiescent Battery Supply Current (V+)	I <sub>+</sub>					40	μΑ
Shutdown Supply Current (VCC)	Icc	SHDN = GND				25	μΑ
Shutdown Supply Current (VDD)	I <sub>DD</sub>	SHDN = GND				5	μΑ
Shutdown Battery Supply Current (V+)	I <sub>+</sub>	SHDN = GND, V <sub>CC</sub> = V <sub>DD</sub> = 0V or 5V				5	μΑ
Reference Voltage	V <sub>REF</sub>	V <sub>CC</sub> = 4.5V to 5.5V, no REF load		1.98		2.02	V
FAULT DETECTION		,					_
V <sub>CC</sub> Undervoltage-Lockout Threshold		Rising edge, hystered disabled below this		4.1		4.4	V



### **ELECTRICAL CHARACTERISTICS (continued)**

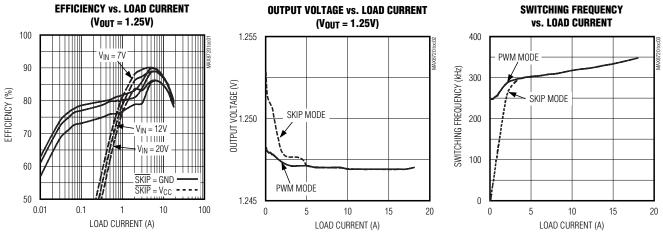
(Circuit of Figure 1, V+ =15V,  $\overline{SHDN} = \overline{SKIP} = V_{DD} = V_{CC} = +5V$ ,  $V_{OUT} = 1.25V$ ,  $T_A = -40^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .) (Note 4)

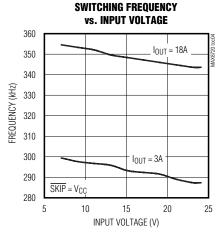
PARAMETER	SYMBOL	CONE	ITIONS	MIN	TYP	MAX	UNITS
Output Overvoltage Trip Threshold				2.20		2.30	V
Output Undervoltage-Protection Trip Threshold		With respect to unloa	ded output voltage	65		75	%
PGOOD Lower Trip Threshold		Measured at FB with output voltage, hyster	•	-17.5		-12.5	%
PGOOD Upper Trip Threshold		Measured at FB with output voltage, hyster	•	+12.5		+17.5	%
CURRENT LIMIT	•			•			•
ILIM Adjustment Range				0.5		V <sub>REF</sub>	V
Current-Limit Threshold (Fixed)	V <sub>LIMIT</sub>	V <sub>PGND</sub> - V <sub>LX</sub> , ILIM = \	/cc	80		115	mV
Current-Limit Threshold	.,	., .,	V <sub>ILIM</sub> = 2.00V	160		240	.,
(Adjustable)	V <sub>LIMIT</sub>	VPGND - VLX	V <sub>ILIM</sub> = 0.50V	33		65	mV
Current-Limit Threshold (Negative)	V <sub>NEG</sub>	V <sub>LX</sub> - V <sub>PGND</sub> , <del>SKIP</del> = ILIM = V <sub>CC</sub>		-140		-85	mV
GATE DRIVERS	•			•			•
DH Gate-Driver On-Resistance	D	DCT I V fore ad to CV	QSOP package			3.5	0
(Note 3)	R <sub>DH</sub>	BST-LX forced to 5V	TQFN package			4.5	Ω
		_ DL, high state	QSOP package			3.5	
DL Gate-Driver On-Resistance (Note 3)	R <sub>DL</sub>	DL, High state	TQFN package			4.0	Ω
(14010-0)		DL, low state				1.0	
INPUTS AND OUTPUTS							
		Logic high		2.4			
SHDN Input Level	VSHDN	Logic low				0.4	V
		No-fault mode		12		15	
Logic Input High Voltage	VIH	D0-D5, SKIP, SUS		2.4			V
Logic Input Low Voltage	V <sub>IL</sub>	D0-D5, SKIP, SUS				0.8	V
Four-Level Input Logic			High	V <sub>CC</sub> - 0.2			
		TON, S0, S1	Open	3.15		3.85	V
			REF	1.65		2.35	
			GND			0.5	

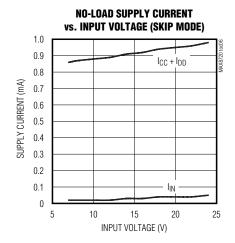
- Note 2: On-time specifications are measured from 50% to 50% at the DH pin, with LX forced to 0, BST forced to 5V, and a 500pF capacitor from DH to LX to simulate external MOSFET gate capacitance. Actual in-circuit times may be different due to MOSFET switching speeds.
- Note 3: Production testing limitations due to package handling require relaxed maximum on-resistance specifications for the thin QFN package. The QSOP and thin QFN package contain the same die, and the thin QFN package imposes no additional resistance in the circuit.
- Note 4: Specifications to -40°C are guaranteed by design, not production tested.

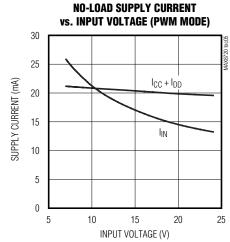
### **Typical Operating Characteristics**

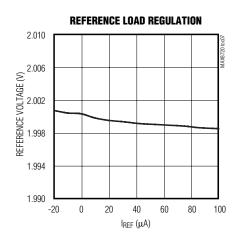
(MAX8720 Circuit of Figure 1,  $V_{IN}$  = 12V,  $V_{DD}$  =  $V_{CC}$  = 5V, TON = open,  $T_A$  = +25°C, unless otherwise noted.)





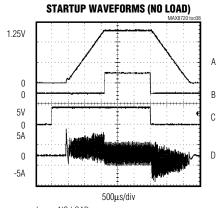




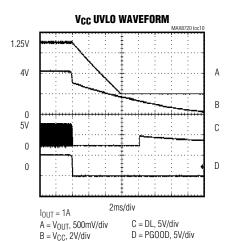


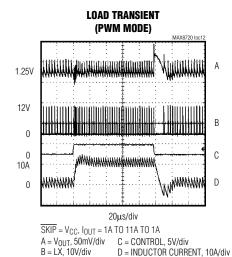
### Typical Operating Characteristics (continued)

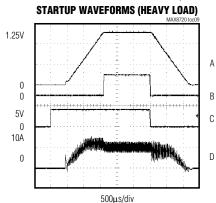
(MAX8720 Circuit of Figure 1,  $V_{IN}$  = 12V,  $V_{DD}$  =  $V_{CC}$  = 5V, TON = open,  $T_A$  = +25°C, unless otherwise noted.)



 $A = V_{\mbox{\scriptsize OUT}}, \mbox{\scriptsize 500mV/div} \quad C = \overline{\mbox{\scriptsize SHDN}}, \mbox{\scriptsize 5V/div}$ B = PGOOD, 5V/div D = INDUCTOR CURRENT, 5A/div



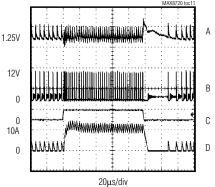




 $I_{OUT} = 10A$ 

 $A = V_{OUT}$ , 500mV/div  $C = \overline{SHDN}$ , 5V/div B = PGOOD, 5V/div D = INDUCTOR CURRENT, 10A/div

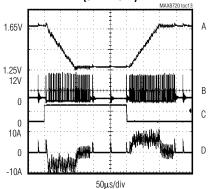
### **LOAD TRANSIENT** (SKIP MODE)



SKIP = GND, I<sub>OUT</sub> = 1A TO 11A TO 1A

 $A = V_{OUT}, \, 50mV/div \quad \ C = CONTROL, \, 5V/div$ D = INDUCTOR CURRENT, 10A/div B = LX, 10V/div

#### **DYNAMIC OUTPUT VOLTAGE TRANSITION** (SKIP MODE)



 $\overline{\text{SKIP}} = \text{GND}, \ I_{OUT} = 0.2 \text{A}$ 

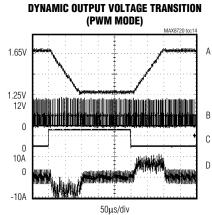
 $A = V_{OUT}$ , 200mV/div C = D4, 5V/div

B = LX, 10V/div

D = INDUCTOR CURRENT, 10A/div

### Typical Operating Characteristics (continued)

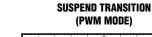
(MAX8720 Circuit of Figure 1, V<sub>IN</sub> = 12V, V<sub>DD</sub> = V<sub>CC</sub> = 5V, TON = open, T<sub>A</sub> = +25°C, unless otherwise noted.)

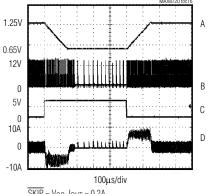


 $\overline{\text{SKIP}} = \text{V}_{\text{CC}}, \, \text{I}_{\text{OUT}} = 0.2 \text{A}$ 

### **SUSPEND TRANSITION** (SKIP MODE) 1.25V 0.65V 12V 0 5V 0 10A -10A 100µs/div SKIP = GND, I<sub>OUT</sub> = 0.2A

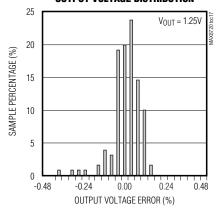
 $\begin{array}{lll} A = V_{OUT}, 500 mV/div & C = D4, 5V/div \\ B = LX, 10V/div & D = INDUCTOR \end{array}$ D = INDUCTOR CURRENT, 10A/div



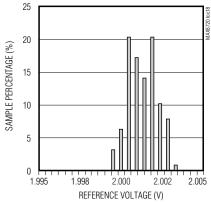


 $\overline{\text{SKIP}} = V_{CC}$ ,  $I_{OUT} = 0.2A$ 

#### **OUTPUT VOLTAGE DISTRIBUTION**







### Pin Description

PIN							
28 QSOP	36 THIN QFN	NAME	FUNCTION				
1	33	V+	Battery Voltage-Sense Connection. Connect V+ to input power source. V+ is used only for PWM one-shot timing. DH on-time is inversely proportional to input voltage over a 2V to 28V range.				
2	34	SHDN	Shutdown Control Input. Connect \$\overline{SHDN}\$ to \$V_{CC}\$ for normal operation. Connect \$\overline{SHDN}\$ to GND to put the controller into its shutdown state. Forcing \$\overline{SHDN}\$ to 12V to 15V disables both the overvoltage-protection and undervoltage-protection circuits and clears the fault latch. Do not connect \$\overline{SHDN}\$ to >15V.				
3	35	TIME	Slew-Rate Adjustment Pin. Connect a resistor from TIME to GND to set the internal slew-rate clock. A 470k $\Omega$ to 22k $\Omega$ resistor sets the clock from 38kHz to 818kHz, f <sub>SLEW</sub> = 150kHz x 120k $\Omega$ / R <sub>TIME</sub> . To reduce inrush current, f <sub>SLEW</sub> = 150kHz x 120k $\Omega$ / 4 x R <sub>TIME</sub> during power-up and power-down transient.				
4	1	FB	Fast Feedback Input. Connect FB to the junction of the external inductor and output- capacitor node (Figure 1).				
5	2	FBS	Feedback Remote-Sense Input. For nonvoltage-positioned circuits, connect FBS to V <sub>OUT</sub> directly at the load. FBS internally connects to the integrator that fine tunes the DC output voltage. For voltage-positioned circuits, connect FBS directly to FB near the IC to disable the FBS remote-sense integrator amplifier. To disable all three integrator amplifiers, connect FBS to V <sub>CC</sub> .				
6	3	CC	Integrator Capacitor Connection. Connect a 47pF to 1000pF (47pF typ) capacitor from CC to AGND to set the integration time constant. CC can be left open if FBS is connected to V <sub>CC</sub> .				
7, 8	4, 5	S0, S1	Suspend-Mode Voltage-Select Input. S0 and S1 are four-level digital inputs that select the suspend-mode VID code for the suspend-mode multiplexer inputs. If SUS is high, the suspend-mode VID code is delivered to the DAC.				
9	7	Vcc	Analog Supply Input. Connect to the system supply voltage (+4.5V to +5.5V) through a series $10\Omega$ resistor. Bypass $V_{CC}$ to analog ground with a $1\mu F$ or greater ceramic capacitor.				
10	8	TON	On-Time Selection Control Input. This is a four-level input that sets the K-factor to determine DH on-time. Connect TON to the following pins for the indicated operation:  GND = 1000kHz  REF = 550kHz  Open = 300kHz  VCC = 200kHz				
11	9	REF	2.0V Reference Voltage Output. Bypass REF to analog ground with a 0.22μF or greater ceramic capacitor. The reference can source up to 50μA for external loads. Loading REF degrades output voltage accuracy according to the REF load regulation error.				
12	10	ILIM	Current-Limit Adjustment. The PGND–LX current-limit threshold defaults to 100mV if ILIM is connected to $V_{CC}$ . In adjustable mode, the current-limit threshold voltage is 1/10th the voltage seen at ILIM over a 0.5V to 3.0V range. The logic threshold for switchover to the 100mV default value is approximately $V_{CC}$ - 1V. Connect ILIM to REF for a fixed 200mV threshold.				

### \_Pin Description (continued)

PIN							
28 QSOP	36 THIN QFN	NAME	FUNCTION				
13	11	GNDS	Ground Remote-Sense Input. For nonvoltage-positioned circuits, connect GNDS to ground directly at the load. GNDS internally connects to the integrator that fine tunes the output voltage. The output voltage rises by an amount of GNDS - AGND. For voltage-positioned circuits, increase the output voltage by biasing GNDS with a resistor-divider from REF to AGND.				
14	12	PGOOD	Open-Drain Power-Good Output. PGOOD is normally high when the output is in regulation. If $V_{FB}$ is not within a $\pm 15\%$ window of the DAC setting, PGOOD is asserted low. During DAC code transitions, PGOOD is forced high for an additional 8 clocks after the slew-rate controller finishes the transition. PGOOD is low during shutdown. PGOOD upper threshold is blanked whenever the MAX8720 is in pulse-skipping mode ( $\overline{SKIP}$ = GND or SUS = high).				
15	_	GND	Analog and Power Ground. Also connects to the current-limit comparator.				
16	16, 17	DL	Low-Side Gate-Driver Output. DL swings from PGND to V <sub>DD</sub> .				
17	19	V <sub>DD</sub>	Supply Voltage Input for the DL Gate Driver. Connect to the system supply voltage (+4.5V to +5.5V). Bypass $V_{DD}$ to power ground with a 1 $\mu$ F or greater ceramic capacitor.				
18	20	SUS	Suspend-Mode Control Input. When SUS is high, the suspend-mode VID code, as programmed by S0 and S1, is delivered to the DAC. Connect SUS to GND if the suspend-mode multiplexer is not used. PGOOD upper threshold is blanked when SUS is high.				
19	21	D0	DAC Code Inputs. D0 is the LSB and D5 is the MSB for the 6-bit DAC.				
20	22	SKIP	Pulse-Skipping Control Input. Connect $\overline{SKIP}$ to VCC for low-noise, forced-PWM mode, or connect $\overline{SKIP}$ to GND to enable pulse-skipping operation. PGOOD upper threshold is blanked when $\overline{SKIP}$ = GND.				
21	23	D5					
22	24	D4					
23	25	D3	DAC Code Inputs. D0 is the LSB and D5 is the MSB for the 6-bit DAC.				
24	26	D2					
25	27	D1					
26	29	BST	Boost Flying-Capacitor Connection. Connect to an external capacitor and diode as shown in Figure 1. An optional resistor in series with BST allows the DH pullup current to be adjusted.				
27	31	LX	Inductor Connection. Connect LX to the switched side of the inductor. LX serves as the lower supply rail for the DH high-side gate driver. It also connects to the current-limit comparator and the skip-mode zero-crossing comparator.				
28	32	DH	High-Side Gate-Driver Output. DH swings from LX to BST.				
	13	AGND	Analog Ground. Connect the backside pad to AGND.				
_	14,15	PGND	Power Ground. Also connects to the current-limit comparator.				
_	6, 18, 28, 30, 36	N.C.	Not internally connected.				

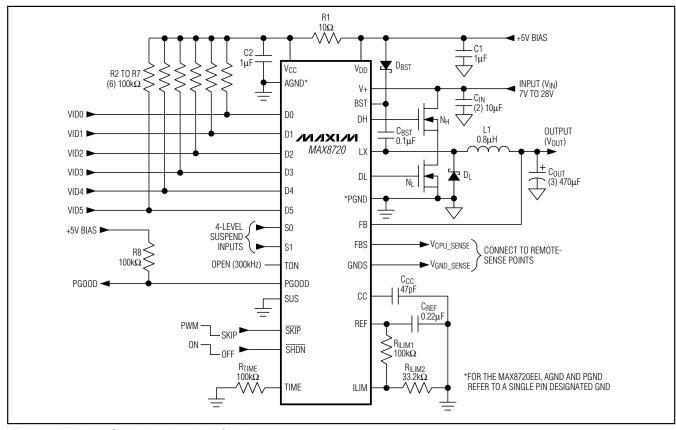


Figure 1. MAX8720 Standard Application Circuit

### **Detailed Description**

The MAX8720 is a constant-on-time, quick-PWM controller with 6-bit VID inputs to dynamically set the output voltage from 0.275V to 1.85V. The MAX8720 standard application circuit (Figure 1) generates a low-voltage 1.25V/15A output typical of low-power CPU and GPU core supplies in a notebook computer. The input supply range is 7V to 24V. See Table 1 for component selections and Table 2 for component manufacturers.

### 5V Bias Supply (VCC and VDD)

The MAX8720 requires an external 5V bias supply in addition to the battery. Typically, this 5V bias supply is the notebook's 95%-efficient, 5V system supply. Keeping the bias supply external to the IC improves efficiency and eliminates the cost associated with the 5V linear regulator that would otherwise be needed to supply the PWM circuit and gate drivers. If stand-alone capability is needed, the 5V supply can be generated with an external linear regulator.

The 5V bias supply must provide  $V_{CC}$  (PWM controller) and  $V_{DD}$  (gate-drive power), so the maximum current drawn is:

$$I_{BIAS} = I_{CC} + f_{SW} (Q_{G(LOW)} + Q_{G(HIGH)})$$
  
= 4mA to 40mA (typ)

where I<sub>CC</sub> is 800 $\mu$ A (typ), f<sub>SW</sub> is the switching frequency, and Q<sub>G(LOW)</sub> and Q<sub>G(HIGH)</sub> are the MOSFET data sheet's total gate-charge specification limits at V<sub>GS</sub> = 5V.

V+ and V<sub>DD</sub> can be connected together if the input power source is a fixed 4.5V to 5.5V supply. If the 5V bias supply is powered up prior to the battery supply, the enable signal (SHDN going from low to high) must be delayed until the battery voltage is present to ensure startup.

#### Reference (REF)

The 2V reference is accurate to  $\pm 0.75\%$  over temperature and load, making REF useful as a precision system reference. Bypass REF to GND with a  $0.22\mu\text{F}$  or greater ceramic capacitor. The reference sources up to  $100\mu\text{A}$  and sinks  $10\mu\text{A}$  to support external loads. Loading the reference reduces the output voltages slightly, because of the reference load regulation error.

Table 1. Component Selection for Standard Applications

COMPONENT	15A/300kHz
Input Voltage	V <sub>IN</sub> = 7V to 24V
Output Voltage	V <sub>OUT</sub> = 1.25V
C <sub>IN</sub> Input Capacitor	(2) 10µF, 25V TDK C3225X7R1E106M AVX 12103D106M Taiyo Yuden TMK325BJ106MM
C <sub>OUT</sub> Output Capacitor	(3) 470μF, 2.5V, 9mΩ low-ESR polymer capacitor Sanyo 2R5TPE470M9
N <sub>H</sub> High-Side MOSFET	Siliconix SI7390DP
N <sub>L</sub> Low-Side MOSFET	Siliconix SI7356DP
D <sub>L</sub> Schottky Rectifier	3A, 30V, 0.45V <sub>f</sub> Nihon EC31QS03L
L1 Inductor	0.8μH, 20A, 4.9mΩ Sumida CDEP104-0R8MC-50

### Free-Running, Constant-On-Time PWM Controller with Input Feed-Forward

The quick-PWM control architecture is a pseudo-fixed-frequency, constant-on-time, current-mode type with voltage feed-forward (Figure 2). This architecture relies on the output filter capacitor's ESR to act as the current-sense resistor, so the output ripple voltage provides the PWM ramp signal. The control algorithm is simple: the high-side switch on-time is determined solely by a one-shot whose period is inversely proportional to input voltage and directly proportional to output voltage. Another one-shot sets a minimum off-time (400ns typ). The on-time one-shot is triggered if the error comparator is low, the low-side switch current is below the current-limit threshold, and the minimum off-time one-shot has timed out.

#### **On-Time One-Shot (TON)**

The heart of the PWM core is the one-shot that sets the high-side switch on-time. This fast, low-jitter, adjustable one-shot includes circuitry that varies the on-time in response to battery and output voltage. The high-side switch on-time is inversely proportional to the battery voltage as measured by the V+ input, and proportional to the output voltage. This algorithm results in a nearly constant switching frequency despite the lack of a fixed-frequency clock generator. The benefits of a con-

**Table 2. Component Suppliers** 

SUPPLIER	WEBSITE
AVX	www.avx.com
Central Semiconductor	www.centralsemi.com
Coiltronics	www.coiltronics.com
Fairchild Semiconductor	www.fairchildsemi.com
Kemet	www.kemet.com
Nihon	www.niec.co.jp
Panasonic	www.panasonic.com/industrial
Sanyo	www.secc.co.jp
Siliconix (Vishay)	www.vishay.com
Sumida	www.sumida.com
Taiyo Yuden	www.t-yuden.com
TDK	www.component.tdk.com
ТОКО	www.tokoam.com

Table 3. K-Factor

TON SETTING	TON FREQUENCY (kHz)	K-FACTOR (μs)			
Vcc	200	5 ±10			
Open	300	$3.3 \pm 10$			
REF	550	1.8 ±12.5			
GND	1000	1.0 ±12.5			

stant switching frequency are twofold: first, the frequency can be selected to avoid noise-sensitive regions such as the 455kHz IF band; second, the inductor ripple-current operating point remains relatively constant, resulting in easy design methodology and predictable output voltage ripple.

On-Time = 
$$K (V_{OUT} + 0.075V) / V_{IN}$$

where K is set by the TON pin-strap connection and 0.075V is an approximation to accommodate the expected drop across the low-side MOSFET switch (Table 3).

The on-time one-shot has good accuracy at the operating points specified in the <code>Electrical Characteristics</code> table ( $\pm 10\%$  at 200kHz and 300kHz, and  $\pm 12\%$  at 550kHz and 1000kHz). On-times at operating points far removed from the conditions specified in the <code>Electrical Characteristics</code> table can vary over a wider range. For example, the 1000kHz setting typically runs approximately 10% slower with inputs much greater than  $\pm 5\%$  due to the very short on-times required.

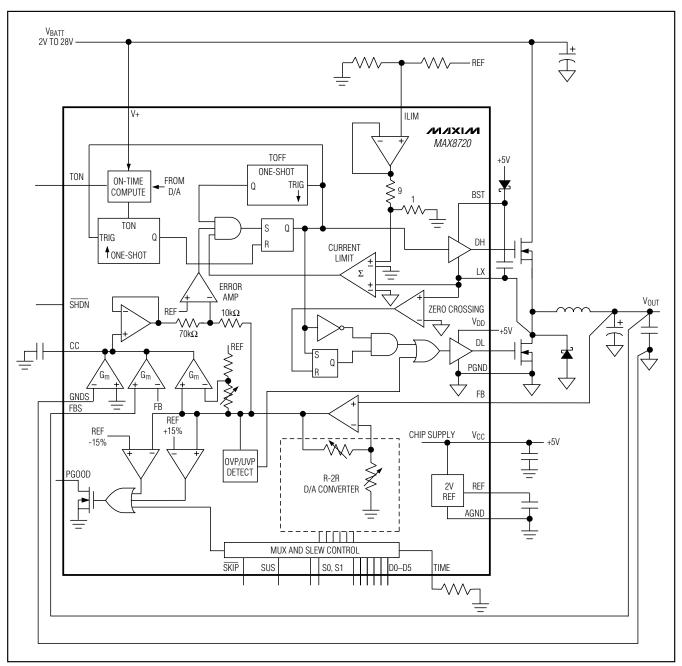


Figure 2. MAX8720 Block Diagram

On-times translate only roughly to switching frequencies. The on-times guaranteed in the *Electrical Characteristics* table are influenced by switching delays in the external high-side MOSFET. Resistive losses, including the inductor, both MOSFETs, output-capacitor

ESR, and PC board copper losses in the output and ground tend to raise the switching frequency at higher output currents. Also, the dead-time effect increases the effective on-time, reducing the switching frequency. It occurs only in PWM mode  $(\overline{\text{SKIP}} = \text{high})$  and during

dynamic output-voltage transitions when the inductor current reverses at light or negative load currents. With reversed inductor current, the inductor's EMF causes LX to go high earlier than normal, extending the on-time by a period equal to the DH-rising dead time.

For loads above the critical conduction point, where the dead-time effect is no longer a factor, the actual switching frequency is:

$$f_{SW} = \frac{V_{OUT} + V_{DIS}}{t_{ON}(V_{IN} + V_{DIS} - V_{CHG})}$$

where V<sub>DIS</sub> is the sum of the parasitic voltage drops in the inductor discharge path, including synchronous rectifier, inductor, and PC board resistances; V<sub>CHG</sub> is the sum of the parasitic voltage drops in the inductor charge path, including high-side switch, inductor, and PC board resistances; and t<sub>ON</sub> is the on-time calculated by the MAX8720.

### Integrator Amplifiers and Output-Voltage Offsets

Three integrator amplifiers provide a fine adjustment to the output regulation point. One amplifier integrates the difference between GNDS and AGND, and a second integrates the difference between FBS and FB. The third amplifier integrates the difference between REF and the DAC output. These three transconductance amplifiers' outputs are directly summed inside the chip, so the integration time constant can be set easily with one capacitor. The  $G_{\rm m}$  of each amplifier is 160 $\mu\rm S$  (typ).

The integrator block has the ability to lower the output voltage by 2% and raise it by 6%. For each amplifier, the differential input voltage range is at least ±70mV total, including DC offset and AC ripple. The integrator corrects for approximately 90% of the total error, due to finite gain.

The FBS amplifier corrects for DC voltage drops in PC board traces and connectors in the output bus path between the DC-DC converter and the load. The GNDS amplifier performs a similar DC correction task for the output ground bus. The third integrator amplifier corrects the small offset of the error amplifier and provides an averaging function that forces Vout to be regulated at the average value of the output ripple waveform.

Integrators have both beneficial and detrimental characteristics. Although they correct for drops due to DC bus resistance and tighten the DC output-voltage tolerance limits by averaging the peak-to-peak output ripple, they can interfere with achieving the fastest possible load-transient response. The fastest transient response is achieved when all three integrators are disabled.

This can work very well if the MAX8720 circuit is placed very close to the CPU. All three integrators can be disabled by connecting FBS to VCC. When the integrators are disabled, CC can be left unconnected, which eliminates a component but leaves GNDS connected to any convenient ground. When the inductor is in continuous conduction, the output voltage has a DC regulation higher than the trip level by 50% of the ripple. In discontinuous conduction ( $\overline{\text{SKIP}} = \text{GND}$ , light loaded), the output voltage has a DC regulation higher than the trip level by approximately 1.5% due to slope compensation.

There is often a connector, or at least many milliohms of PC board trace resistance, between the DC-DC converter and the CPU. In these cases, the best strategy is to place most of the bulk bypass capacitors close to the CPU, with just one capacitor on the other side of the connector near the MAX8720 to control ripple if the CPU card is unplugged. In this situation, the remotesense lines (GNDS and FBS) and integrators provide a real benefit.

### Forced-PWM Mode (SKIP = High)

The low-noise forced-PWM mode (SKIP = high) disables the zero-crossing comparator, allowing the inductor current to reverse at light loads. This causes the low-side gate-drive waveform to become the complement of the high-side gate-drive waveform. The benefit of forced-PWM mode is to keep the switching frequency fairly constant, but it comes at a cost: the noload battery current can be 10mA to 40mA, depending on the external MOSFETs and switching frequency.

Forced-PWM mode is required during downward output-voltage transitions. The MAX8720 uses PWM mode during all transitions, but only while the slew-rate controller is active. Due to voltage positioning, when a transition uses high negative inductor current, the output voltage does not settle to its final intended value until well after the slew-rate controller terminates. Because of this it is possible, at very high negative slew currents, for the output to end up high enough to cause PGOOD to go low.

Thus, it is necessary to use forced-PWM mode during all negative transitions. Most applications should use PWM mode exclusively, although there is some benefit to using skip mode while in the low-power suspend state.

### Automatic Pulse-Skipping Switchover (SKIP = GND)

In skip mode (SKIP = GND), an inherent automatic switchover to PFM takes place at light loads (Figure 3). This switchover is affected by a comparator that truncates the low-side switch on-time at the inductor current's zero crossing. This mechanism causes the

threshold between pulse-skipping PFM and nonskipping PWM operation to coincide with the boundary between continuous and discontinuous inductor-current operation. The load-current level at which PFM/PWM crossover occurs, ILOAD(SKIP), is equal to half the peak-to-peak ripple current, which is a function of the inductor value (Figure 3). For a 7V to 24V battery range, this threshold is relatively constant, with only a minor dependence on battery voltage:

$$I_{LOAD(SKIP)} = \frac{KV_{OUT}(V_{IN} - V_{OUT})}{2LV_{IN}}$$

where K is the on-time scale factor (Table 2). For example, in the standard application circuit this becomes:

$$I_{LOAD(SKIP)} = \frac{3.3\mu s \times 1.25V(12V - 1.25V)}{2 \times 0.8\mu H \times 12V} = 2.31A$$

The crossover point occurs at a lower value if a swinging (soft-saturation) inductor is used.

The switching waveforms may appear noisy and asynchronous when light loading causes pulse-skipping operation, but this is a normal operating condition that results in high light-load efficiency. Trade-offs in PFM noise vs. light-load efficiency are made by varying the inductor value. Generally, low inductor values produce a broader efficiency vs. load curve, while higher values result in higher full-load efficiency (assuming that the coil resistance remains fixed) and less output voltage ripple. Penalties for using higher inductor values include larger physical size and degraded load-transient response, especially at low input-voltage levels.

#### **Current-Limit Circuit**

The current-limit circuit employs a unique "valley" current-sensing algorithm that uses the on-resistance of the low-side MOSFET as a current-sensing element. If the current-sense signal is above the current-limit threshold, the PWM is not allowed to initiate a new cycle (Figure 4). The actual peak current is greater than the current-limit threshold by an amount equal to the inductor ripple current. Therefore, the exact current-limit characteristic and maximum load capability are a function of the MOSFET on-resistance, inductor value, and battery voltage. The reward for this uncertainty is robust, lossless overcurrent sensing. When combined with the undervoltage-protection circuit, this current-limit method is effective in almost every circumstance.

There is also a negative current limit that prevents excessive reverse inductor currents when V<sub>OUT</sub> is

sinking current. The negative current-limit threshold is set to approximately 120% of the positive current limit, and therefore tracks the positive current limit when ILIM is adjusted.

The current-limit threshold is adjusted with an external resistor-divider at ILIM. The current-limit threshold voltage adjustment range is from 50mV to 200mV. In the adjustable mode, the current-limit threshold voltage is precisely 1/10th the voltage seen at ILIM. The threshold defaults to 100mV when ILIM is connected to VCC. The logic threshold for switchover to the 100mV default value is approximately VCC - 1V.

Carefully observe the PC board layout guidelines to ensure that noise and DC errors do not corrupt the current-sense signals seen by LX and PGND. Place the IC close to the low-side MOSFET with short, direct traces, making a Kelvin-sense connection to the source and drain terminals.

#### **MOSFET Gate Drivers (DH, DL)**

The DH and DL drivers are optimized for driving moderate-sized high-side and larger low-side power MOSFETs. This is consistent with the low duty factor seen in the notebook CPU environment, where a large V<sub>IN</sub> - V<sub>OUT</sub> differential exists. An adaptive dead-time circuit monitors the DL output and prevents the high-side FET from turning on until DL is fully off. There must be a low-resistance, low-inductance path from the DL driver to the MOSFET gate for the adaptive dead-time circuit to work properly. Otherwise, the sense circuitry in the MAX8720 interprets the MOSFET gate as "off" while there is actually still charge left on the gate. Use very short, wide traces measuring 10 to 20 squares (50 to 100 mils wide if the MOSFET is 1 in from the MAX8720).

The dead time at the other edge (DH turning off) is determined by a fixed 35ns (typ) internal delay.

The internal pulldown transistor that drives DL low is robust, with a  $0.4\Omega$  (typ) on-resistance. This helps prevent DL from being pulled up during the fast rise time of the inductor node, due to capacitive coupling from the drain to the gate of the low-side synchronous-rectifier MOSFET. Applications with high input voltages and long, inductive DL traces may require additional gate-to-source capacitance to ensure fast-rising LX edges do not pull up the low-side MOSFET's gate voltage, causing shoot-through currents. The capacitive coupling between LX and DL created by the MOSFET's gate-to-drain capacitance (CRSS), gate-to-source capacitance (CISS - CRSS), and additional board parasitics should not exceed the minimum threshold voltage:

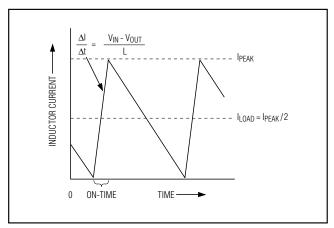


Figure 3. Pulse-Skipping/Discontinuous Crossover Point

$$V_{GS(TH)} > V_{IN} \left( \frac{C_{RSS}}{C_{ISS}} \right)$$

Lot-to-lot variation of the threshold voltage can cause problems in marginal designs. Typically, adding 4700pF between DL and power ground (C<sub>NL</sub> in Figure 5), close to the low-side MOSFETs, greatly reduces coupling. Do not exceed 22nF of total gate capacitance to prevent excessive turn-off delays.

Alternatively, shoot-through currents may be caused by a combination of fast high-side MOSFETs and slow low-side MOSFETs. If the turn-off delay time of the low-side MOSFET is too long, the high-side MOSFETs can turn on before the low-side MOSFETs have actually turned off. Adding a resistor less than  $5\Omega$  in series with BST slows down the high-side MOSFETs' turn-on time, eliminating the shoot-through currents without degrading the turn-off time (RBST in Figure 5). Slowing down the high-side MOSFETs also reduces the LX node rise time, thereby reducing EMI and high-frequency coupling responsible for switching noise.

### V<sub>CC</sub> POR and UVLO

Power-on reset (POR) occurs when V<sub>CC</sub> rises above approximately 2V, resetting the fault latch and preparing the PWM for operation. V<sub>CC</sub> undervoltage-lockout (UVLO) circuitry inhibits switching, forces PGOOD low, and forces the DL gate driver low. When V<sub>CC</sub> rises above 4.2V, the DAC inputs are sampled and the output voltage begins to slew to the DAC setting.

If  $V_{CC}$  drops low enough to trip the UVLO comparator, it is assumed that there is not enough supply voltage to make valid decisions. The MAX8720 immediately forces both DH and DL low. The output discharges to 0V at a

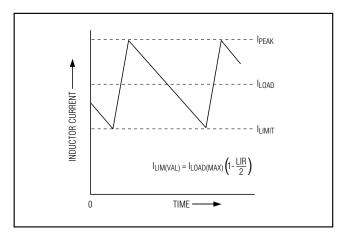


Figure 4. Valley Current-Limit Threshold

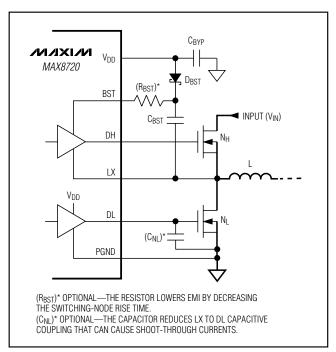


Figure 5. Reducing the Switching-Node Rise Time

rate dependent on the load and the total output capacitance. This prevents negative output voltages, eliminating the need for a Schottky diode to GND at the output.

For automatic startup, the battery voltage should be present before V<sub>CC</sub>. If the MAX8720 attempts to bring the output into regulation without the battery voltage present, the fault latch trips. The  $\overline{\text{SHDN}}$  pin can be togaled to reset the fault latch.

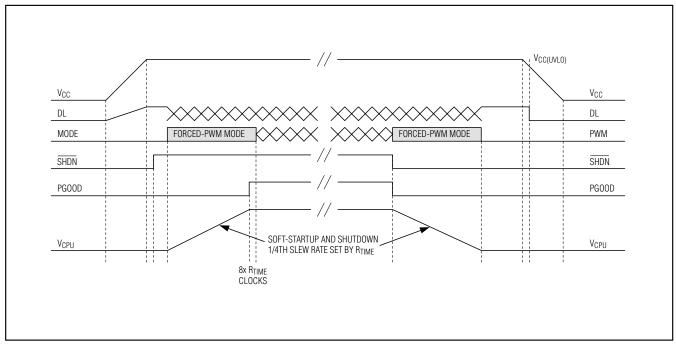


Figure 6. Soft-Startup and Soft-Shutdown

#### Soft-Startup and Soft-Shutdown (SHDN)

When SHDN goes low, the MAX8720 enters low-power shutdown mode. PGOOD goes low immediately. The output voltage ramps down to 0V in 25mV steps at 1/4th the clock rate set by RTIME. The slow rampdown of the output voltage results in smaller negative inductor currents, eliminating negative voltages on the output. When the DAC reaches the 0V setting, DL goes high, DH goes low, the reference is turned off, and the supply current drops to approximately 10µA.

When SHDN goes high, the reference powers up, and after the reference UVLO is passed, the DAC target is evaluated and switching begins. The slew-rate controller ramps up from 0V in 25mV steps at 1/4th the clock rate set by RTIME to the currently selected code value (based on SUS). Full output current is available immediately. PGOOD goes high after the slew-rate controller has terminated and the output voltage is in regulation.

#### **Nominal Output Voltage Setting**

The MAX8720 uses a multiplexer that selects from two different inputs (Figure 7)—the VID DAC inputs or the suspend-mode S0, S1 inputs. On startup, the MAX8720 slews the target voltage from ground to either the decoded D0–D5 (SUS = low) voltage or the S0, S1 voltage (SUS = high).

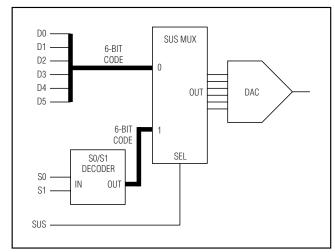


Figure 7. Internal Multiplexers Functional Diagram

### DAC Inputs (D0-D5)

The digital-to-analog converter (DAC) programs the output voltage. It typically receives a preset digital code from the CPU pins, which are either hardwired to GND or left open-circuit. They can also be driven by digital logic, general-purpose I/O, or an external mux. Do not leave D0–D5 floating—use  $1M\Omega$  or less pullup resistors if the inputs may float. D0–D5 can be changed while the

Table 4. Output Voltage vs. DAC Codes

D5	D4	D3	D2	D1	D0	Vout		D5	D4	D3	D2	D1	D0	Vout
0	0	0	0	0	0	1.850		1	0	0	0	0	0	1.050
0	0	0	0	0	1	1.825		1	0	0	0	0	1	1.025
0	0	0	0	1	0	1.800		1	0	0	0	1	0	1.000
0	0	0	0	1	1	1.775		1	0	0	0	1	1	0.975
0	0	0	1	0	0	1.750		1	0	0	1	0	0	0.950
0	0	0	1	0	1	1.725		1	0	0	1	0	1	0.925
0	0	0	1	1	0	1.700		1	0	0	1	1	0	0.900
0	0	0	1	1	1	1.675		1	0	0	1	1	1	0.875
0	0	1	0	0	0	1.650		1	0	1	0	0	0	0.850
0	0	1	0	0	1	1.625		1	0	1	0	0	1	0.825
0	0	1	0	1	0	1.600		1	0	1	0	1	0	0.800
0	0	1	0	1	1	1.575		1	0	1	0	1	1	0.775
0	0	1	1	0	0	1.550		1	0	1	1	0	0	0.750
0	0	1	1	0	1	1.525		1	0	1	1	0	1	0.725
0	0	1	1	1	0	1.500		1	0	1	1	1	0	0.700
0	0	1	1	1	1	1.475		1	0	1	1	1	1	0.675
0	1	0	0	0	0	1.450		1	1	0	0	0	0	0.650
0	1	0	0	0	1	1.425		1	1	0	0	0	1	0.625
0	1	0	0	1	0	1.400		1	1	0	0	1	0	0.600
0	1	0	0	1	1	1.375		1	1	0	0	1	1	0.575
0	1	0	1	0	0	1.350		1	1	0	1	0	0	0.550
0	1	0	1	0	1	1.325		1	1	0	1	0	1	0.525
0	1	0	1	1	0	1.300		1	1	0	1	1	0	0.500
0	1	0	1	1	1	1.275		1	1	0	1	1	1	0.475
0	1	1	0	0	0	1.250		1	1	1	0	0	0	0.450
0	1	1	0	0	1	1.225		1	1	1	0	0	1	0.425
0	1	1	0	1	0	1.200		1	1	1	0	1	0	0.400
0	1	1	0	1	1	1.175		1	1	1	0	1	1	0.375
0	1	1	1	0	0	1.150		1	1	1	1	0	0	0.350
0	1	1	1	0	1	1.125	]	1	1	1	1	0	1	0.325
0	1	1	1	1	0	1.100		1	1	1	1	1	0	0.300
0	1	1	1	1	1	1.075		1	1	1	1	1	1	0.275

SMPS is active, initiating a transition to a new output voltage level. If this mode of DAC control is used, connect SUS low. Change D0–D5 together, avoiding greater than 50ns skew between bits. Otherwise, incorrect DAC readings may cause a partial transition to the wrong voltage level, followed by the intended transition to the correct voltage level, lengthening the overall transition time. The available DAC codes and resulting output voltages are shown in Table 4.

#### Suspend Mode (S0, S1, SUS)

When the CPU enters low-power suspend mode, the processor sets the regulator to a lower output voltage to reduce power consumption. The MAX8720 includes a suspend-mode input (S0, S1) and a digital SUS control input. The suspend voltage is programmed using the 4-level S0, S1 inputs (Table 5). The suspend voltage adjustment range is from 0.275V to 0.650V.

Table 5. Suspend-Mode DAC Codes

S1	S0	Vout	S1	S0	Vout
GND	GND	0.650	OPEN	GND	0.450
GND	REF	0.625	OPEN	REF	0.425
GND	OPEN	0.600	OPEN	OPEN	0.400
GND	Vcc	0.575	OPEN	Vcc	0.375
REF	GND	0.550	V <sub>C</sub> C	GND	0.350
REF	REF	0.525	V <sub>CC</sub>	REF	0.325
REF	OPEN	0.500	V <sub>C</sub> C	OPEN	0.300
REF	Vcc	0.475	V <sub>C</sub> C	Vcc	0.275

When the CPU suspends operation (SUS = high), the controller overrides the 6-bit VID DAC code set by D0–D5, and slews the output voltage to the target voltage set by the S0, S1 inputs. During the transition, the MAX8720 blanks both PGOOD thresholds (PGOOD forced high impedance) until the slew-rate controller reaches the suspend-mode voltage, plus 8 extra RTIME clocks. After this blanking time expires, the MAX8720 automatically switches to a pulse-skipping control scheme regardless of  $\overline{\rm SKIP}$ .

### **Output-Voltage-Transition Timing**

The MAX8720 is designed to perform output-voltage transitions in a controlled manner, automatically minimizing input surge currents. This feature allows the circuit designer to achieve nearly ideal transitions, guaranteeing just-in-time arrival at the new output-voltage level with the lowest possible peak currents for a given output capacitance. This makes the IC ideal for CPUs and GPUs that operate at different voltages.

At the beginning of an output-voltage transition (VID change or SUS level change), the MAX8720 enters forced-PWM mode and blanks the PGOOD output (forced high impedance). PGOOD remains blanked during the transition and is re-enabled when the slew-rate controller has set the internal DAC to the final value and 8 additional slew-rate clock periods have passed. The slew-rate clock frequency (set by resistor RTIME) must be set fast enough to ensure that the longest required transition is completed within the allowed transition time.

The output-voltage transition is performed in 25mV steps, preceded by a delay and followed by one addi-

tional clock period. The total time for a transition depends on R<sub>TIME</sub>, the voltage difference, and the accuracy of the MAX8720's slew-rate clock, and is not dependent on the total output capacitance. The greater the output capacitance, the higher the surge current required for the transition. The MAX8720 automatically controls the current to the minimum level required to complete the transition in the calculated time, as long as the surge current is less than the current limit set by ILIM. The transition time is given by:

$$t_{TRANS} = \frac{IV_{OLD} - V_{NEW}I}{25mV \times f_{SLEW}} + t_{DELAY}$$

where fslew = 150kHz x 120k $\Omega$  / RTIME, VolD is the original DAC setting, VNEW is the new DAC setting, and tDELAY ranges from zero to a maximum of 2 / fslew. See Time Frequency Accuracy in the *Electrical Characteristics* table for fslew accuracy. The practical range of RTIME is 22k $\Omega$  to 470k $\Omega$ , corresponding to 1.22µs to 26µs per 25mV step. Although the DAC takes discrete 25mV steps, the output filter makes the transitions relatively smooth. The average inductor current required to make an output-voltage transition is:

$$I_{L(AVE)} = C_{OUT} \times 25mV \times f_{SLEW}$$

### Suspend Transition (Forced-PWM Operation Selected)

When the MAX8720 enters suspend mode while configured for forced-PWM operation (SKIP pulled high), the controller ramps the output voltage down to the S0, S1 programmed voltage at the slew rate determined by RTIME. The controller blanks PGOOD (forced high impedance) until the transition is completed plus 8 extra RTIME clocks—the internal target voltage equals the selected S0, S1 DAC voltage. After this blanking time expires, the controller enters pulse-skipping operation.

When exiting suspend mode (SUS pulled low), the MAX8720 immediately enters forced-PWM mode and ramps the output up at the slew rate set by RTIME. The controller blanks PGOOD (forced high impedance) until the transition is completed plus 8 extra RTIME clocks—the internal target voltage equals the selected D0-D5 DAC voltage.

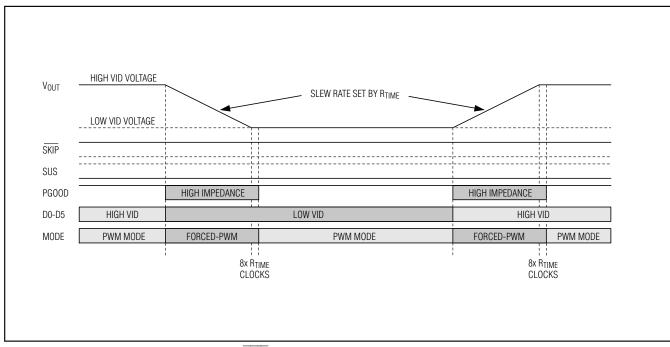


Figure 8. VID Transition in Forced-PWM Mode ( $\overline{SKIP} = High$ )

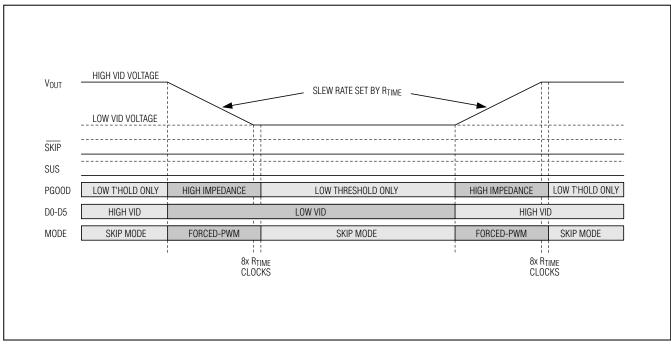


Figure 9. VID Transition in Pulse-Skipping Mode ( $\overline{SKIP} = GND$ )

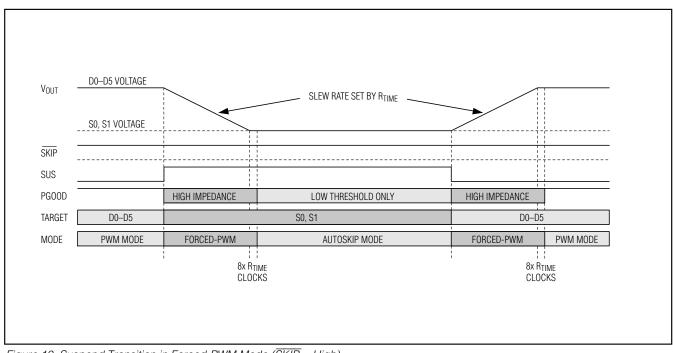


Figure 10. Suspend Transition in Forced-PWM Mode ( $\overline{SKIP}$  = High)

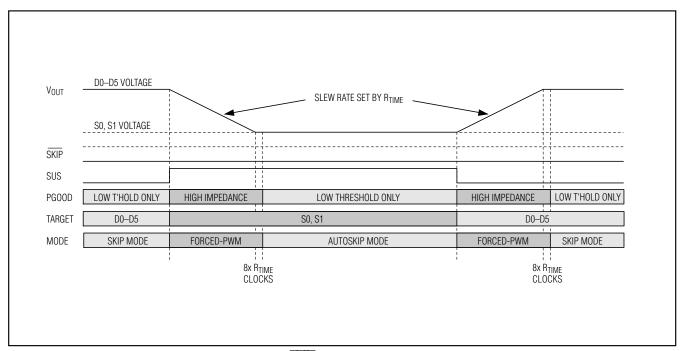


Figure 11. Suspend Transition in Pulse-Skipping Mode (SKIP = GND)

### Suspend Transition (Pulse-Skipping Operation Selected)

If the MAX8720 is configured for pulse-skipping operation (SKIP = GND) when SUS goes high, the MAX8720 immediately enters forced-PWM mode, ramping the output voltage down to the S0, S1 programmed voltage at the slew rate determined by RTIME. The controller blanks PGOOD (forced high impedance) until the transition is completed plus 8 extra RTIME clocks—the internal target voltage equals the selected S0, S1 DAC voltage. After this blanking time expires, the controller enters pulse-skipping operation.

When exiting suspend mode (SUS pulled low), the MAX8720 immediately enters forced-PWM mode and ramps the output up at the slew rate set by R<sub>TIME</sub>. The controller blanks PGOOD (forced high impedance) until the transition is completed plus 8 extra R<sub>TIME</sub> clocks—the internal target voltage equals the selected D0–D5 DAC voltage. After this blanking time expires, the controller returns to pulse-skipping operation.

### **Output Overvoltage Protection**

The overvoltage-protection (OVP) circuit is designed to protect the CPU against a shorted high-side MOSFET by drawing high current and blowing the battery fuse. The output voltage is continuously monitored for overvoltage. If the output is more than 2.25V, OVP is triggered and the circuit shuts down. The DL low-side gate-driver output is then latched high until SHDN is toggled or VCC power is cycled below 1V. This action turns on the synchronous-rectifier MOSFET with 100% duty and, in turn, rapidly discharges the output filter capacitor and forces the output to ground. If the condition that caused the overvoltage (such as a shorted high-side MOSFET) persists, the battery fuse blows. DL is also kept high continuously in shutdown when VCC is above the UVLO threshold.

#### **Output Undervoltage Shutdown**

The output UVP function is similar to foldback current limiting, but employs a timer rather than a variable current limit. If the MAX8720 output voltage is under 70% of the nominal value, the PWM is latched off and won't restart until VCC power is cycled or \$\overline{SHDN}\$ is toggled. To allow startup, UVP is ignored until the internal DAC reaches the final target plus 8 extra RTIME clocks.

UVP can be defeated through the no-fault test mode (see the *No-Fault Test Mode* section).

#### **No-Fault Test Mode**

The over/undervoltage-protection features can complicate the process of debugging prototype breadboards since there are (at most) a few milliseconds in which to

determine what went wrong. Therefore, a test mode is provided to disable the OVP, UVP, and thermal-shutdown features, and clear the fault latch if it has been set. The no-fault test mode is entered by forcing 12V to 15V on SHDN.

### **Design Procedure**

Firmly establish the input voltage range and maximum load current before choosing a switching frequency and inductor operating point (ripple-current ratio). The primary design trade-off lies in choosing a good switching frequency and inductor operating point, and the following four factors dictate the rest of the design:

- Input Voltage Range. The maximum value (VIN(MAX)) must accommodate the worst-case, high AC-adapter voltage. The minimum value (VIN(MIN)) must account for the lowest battery voltage after drops due to connectors, fuses, and battery selector switches. If there is a choice at all, lower input voltages result in better efficiency.
- Maximum Load Current. There are two values to consider. The peak load current (ILOAD(MAX)) determines the instantaneous component stresses and filtering requirements and thus drives output-capacitor selection, inductor saturation rating, and the design of the current-limit circuit. The continuous load current (ILOAD) determines the thermal stresses and thus drives the selection of input capacitors, MOSFETs, and other critical heat-contributing components.
- **Switching Frequency.** This choice determines the basic trade-off between size and efficiency. The optimal frequency is largely a function of maximum input voltage, due to MOSFET switching losses that are proportional to frequency and V<sub>IN</sub><sup>2</sup>. The optimum frequency is also a moving target, due to rapid improvements in MOSFET technology that are making higher frequencies more practical.
- Inductor Operating Point. This choice provides trade-offs between size vs. efficiency, and transient response vs. output ripple. Low inductor values provide better transient response and smaller physical size, but also result in lower efficiency and higher output ripple due to increased ripple currents. The minimum practical inductor value is one that causes the circuit to operate at the edge of critical conduction (where the inductor current just touches zero with every cycle at maximum load). Inductor values lower than this grant no further size-reduction benefit.

The optimum operating point is usually found between 20% and 50% ripple current. When pulse skipping (SKIP low and light loads), the inductor

value also determines the load-current value at which PFM/PWM switchover occurs.

#### **Inductor Selection**

The switching frequency and inductor operating point determine the inductor value as follows:

$$L = \frac{V_{OUT}(V_{IN} - V_{OUT})}{V_{IN} f_{SW} I_{LOAD(MAX)} LIR}$$

For example: I<sub>LOAD(MAX)</sub> = 15A, V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 1.25V, f<sub>SW</sub> = 300kHz, 30% ripple current or LIR = 0.3

$$L = \frac{1.25V \times (12V - 1.25V)}{1.2V \times 300k \text{ Hz} \times 15A \times 0.3} = 0.83\mu\text{H}$$

Find a low-loss inductor with the lowest possible DC resistance that fits in the allotted dimensions. Ferrite cores are often the best choice, although powdered iron is inexpensive and can work well at 200kHz. The core must be large enough not to saturate at the peak inductor current (IPEAK):

$$I_{PEAK} = I_{LOAD(MAX)} \left( 1 + \frac{LIR}{2} \right)$$

Most inductor manufacturers provide inductors in standard values, such as 1.0 $\mu$ H, 1.5 $\mu$ H, 2.2 $\mu$ H, 3.3 $\mu$ H, etc. Also look for nonstandard values, which can provide a better compromise in LIR across the input voltage range. If using a swinging inductor (where the no-load inductance decreases linearly with increasing current), evaluate the LIR with properly scaled inductance values.

#### **Transient Response**

The inductor ripple current also impacts transient-response performance, especially at low  $V_{\text{IN}}$  -  $V_{\text{OUT}}$  differentials. Low inductor values allow the inductor current to slew faster, replenishing charge removed from the output filter capacitors by a sudden load step. The total output-voltage sag is the sum of the voltage sag while the inductor is ramping up and the voltage sag before the next pulse can occur.

$$V_{SAG} = \frac{L(\Delta I_{LOAD(MAX)}) \left(K \frac{V_{OUT}}{V_{IN}} + t_{OFF(MIN)}\right)}{2C_{OUT} V_{OUT} \left[K \left(\frac{V_{IN} - V_{OUT}}{V_{IN}}\right) - t_{OFF(MIN)}\right]}$$

where toff(MIN) is the minimum off-time (see the *Electrical Characteristics*) and K is from Table 3.

The amount of overshoot during a full-load to no-load transient due to stored inductor energy can be calculated as:

$$V_{SOAR} \approx \frac{(\Delta I_{LOAD(MAX)})^2 L}{2C_{OUT} V_{OUT}}$$

### **Setting the Current Limit**

The minimum current-limit threshold must be great enough to support the maximum load current when the current limit is at the minimum tolerance value. The peak inductor current occurs at ILOAD(MAX) plus half the ripple current; therefore:

$$I_{LIMIT(LOW)} > I_{LOAD(MAX)} \left(1 - \frac{LIR}{2}\right)$$

where I<sub>LIMIT</sub>(LOW) equals the minimum current-limit threshold voltage divided by the R<sub>DS</sub>(ON) of N<sub>L</sub>. For the 100mV default setting, the minimum current-limit threshold is 90mV.

Connect ILIM to  $V_{CC}$  for a default 100mV current-limit threshold. For an adjustable threshold, connect a resistor-divider from REF to GND, with ILIM connected to the center tap. The external adjustment range of 0.5V to 2.0V corresponds to a current-limit threshold of 50mV to 200mV. When adjusting the current limit, use 1% tolerance resistors and a 10 $\mu$ A divider current to prevent a significant increase of errors in the current-limit tolerance.

#### **Output Capacitor Selection**

The output filter capacitor must have low enough equivalent series resistance (ESR) to meet output ripple and load-transient requirements, yet have high enough ESR to satisfy stability requirements. The output capacitance must be high enough to absorb the inductor energy while transitioning from full-load to no-load conditions without tripping the overvoltage fault protection. When using high-capacitance, low-ESR capacitors (see the *Output-Capacitor Stability Requirements* section), the filter capacitor's ESR dominates the output voltage ripple. Thus, the output capacitor's size depends on the maximum ESR required to meet the output-voltage-ripple (VRIPPLE(P-P)) specifications:

In CPU V<sub>CORE</sub> converters and other applications where the output is subject to violent load transients, the output capacitor's size typically depends on how much ESR is needed to prevent the output from dipping too

low under a load transient. Ignoring the sag due to finite capacitance:

The actual capacitance value required relates to the physical size needed to achieve low ESR, as well as to the chemistry of the capacitor technology. Thus, the capacitor is usually selected by ESR and voltage rating rather than by capacitance value (this is true of tantalums, OS-CONs, polymers, and other electrolytics).

When using low-capacity filter capacitors, such as ceramic capacitors, size is usually determined by the capacity needed to prevent VSAG and VSOAR from causing problems during load transients. Generally, once enough capacitance is added to meet the overshoot requirement, undershoot at the rising load edge is no longer a problem (see the VSAG and VSOAR equations in the *Transient Response* section). However, low-capacity filter capacitors typically have high-ESR zeros that may affect the overall stability (see the *Output-Capacitor Stability Considerations* section).

#### Output-Capacitor Stability Considerations

Stability is determined by the value of the ESR zero relative to the switching frequency. The boundary of instability is given by the following equation:

$$f_{ESR} \le \frac{f_{SW}}{\pi}$$
 where  $f_{ESR} = \frac{1}{2\pi R_{ESR} C_{OUT}}$ 

A voltage-positioned circuit has the ESR zero frequency lowered due to the external resistor in series with the output-capacitor ESR, guaranteeing stability. For a voltage-positioned circuit, the minimum ESR requirement of the output capacitor is reduced by the voltage-positioning resistor value.

The boundary condition of instability is given by the following equation:

RESR x Cout 
$$\geq$$
 1 / (2 x fsw)

For good phase margin, it is recommended to increase the equivalent RC time constant by a factor of two. The standard application circuit (Figure 1) operating at 300kHz with  $C_{OUT}=1410\mu F$  and  $R_{ESR}=3m\Omega$  easily meets this requirement.

The easiest method for checking stability is to apply a very fast zero-to-max load transient and carefully observe the output-voltage-ripple envelope for overshoot and ringing. It can help to simultaneously monitor the inductor current with an AC current probe. Do not allow more than one cycle of ringing after the initial step-response under/overshoot.

Do not put high-value ceramic capacitors directly across the feedback sense point without taking precautions to ensure stability. Large ceramic capacitors can have a high-ESR zero frequency and cause erratic, unstable operation. However, it is easy to add enough series resistance by placing the capacitors a couple of inches downstream from the feedback sense point, which should be as close as possible to the inductor.

Unstable operation manifests itself in two related but distinctly different ways: double pulsing and fast-feed-back loop instability. Double pulsing occurs due to noise on the output or because the ESR is so low that there is not enough voltage ramp in the output voltage signal. This "fools" the error comparator into triggering a new cycle immediately after the 400ns minimum off-time period has expired. Double pulsing is more of a nuisance than harmful, resulting in nothing worse than increased output ripple. However, it can indicate the possible presence of loop instability due to insufficient ESR. Loop instability can result in oscillations at the output after line or load steps. Such perturbations are usually damped, but can cause the output voltage to rise above or fall below the tolerance limits.

### **Input Capacitor Selection**

The input capacitor must meet the ripple-current requirement (I<sub>RMS</sub>) imposed by the switching currents defined by the following equation:

$$I_{RMS} = \frac{I_{OUT(MAX)}}{V_{IN}} \sqrt{V_{OUT}(V_{IN} - V_{OUT})}$$

For most applications, nontantalum chemistries (ceramic or OS-CON) are preferred due to their resistance to inrush surge currents typical of systems with a switch or a connector in series with the battery. If the MAX8720 is operated as the second stage of a two-stage power-conversion system, tantalum input capacitors are acceptable. In either configuration, choose an input capacitor that exhibits less than +10°C temperature rise at the RMS input current for optimal reliability and lifetime.

#### **Power MOSFET Selection**

Most of the following MOSFET guidelines focus on the challenge of obtaining high load-current capability when using high-voltage (>20V) AC adapters. Low-current applications usually require less attention.

The high-side MOSFET (N<sub>H</sub>) must be able to dissipate the resistive losses plus the switching losses at both  $V_{IN(MIN)}$  and  $V_{IN(MAX)}$ . Ideally, the losses at  $V_{IN(MAX)}$ , with lower losses in between. If the losses at  $V_{IN(MIN)}$  are